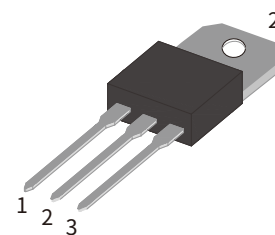


FEATURES

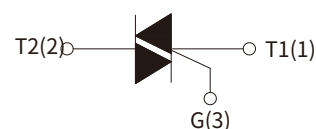
- | Direct interfacing to logic level ICs
- | Direct interfacing to low power gate drive circuits
- | High blocking voltage capability
- | Planar passivated for voltage ruggedness and reliability
- | Triggering in all four quadrant



TO-220B(Non-Ins)

APPLICATIONS

- | General purpose motor control circuits
- | Phase control operations in light dimmers and motor speed controllers
- | Home appliances



Schematic Symbol

ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$)		V_{DRM}	800	V
Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$)		V_{RRM}	800	V
RMS on-state current ($T_c=95^\circ\text{C}$)		$I_{\text{T(RMS)}}$	8	A
Non repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$)		I_{TSM}	65	
I^2t value for fusing ($t_p=10\text{ms}$)		I^2t	21	A^2S
Critical rate of rise of on-state current ($I_G=2 \times I_{\text{GT}}$)	I - II - III	di/dt	50	$\text{A}/\mu\text{s}$
	IV		10	
Peak gate current		I_{GM}	2	A
Average gate power dissipation		$P_{\text{G(AV)}}$	0.5	W
Peak gate power		P_{GM}	5	W
Operating junction temperature range		T_j	-40~+125	$^\circ\text{C}$
Storage junction temperature range		T_{STG}	-40~+150	

ELECTRICAL CHARACTERISTICS (T_j=25°C unless otherwise specified)

Symbol	Test Condition	Quadrant	Value				Unit
			D	E	F	G	
I _{GT}	V _D =12V	I - II - III	≤5	≤10	≤25	≤50	mA
		IV	≤10	≤25	≤70	≤100	
V _{GT}		ALL	≤1.3				V
V _{GD}	V _D =V _{DRM} , R _L =3.3KΩ, T _j =125°C		≥0.2				V
I _H	I _T =100mA		≤10	≤15	≤40	≤60	mA
I _L	I _G =1.2I _{GT}	I - III	≤10	≤20	≤50	≤70	
		II - IV	≤20	≤30	≤70	≤100	
dV _D /dt	V _D =67%V _{DRM} , T _j =125°C		≥20	≥50	≥50	≥200	V/μs
V _{TM}	I _{TM} =10A, tp=380μs		≤1.6				V
I _{DRM}	V _D =V _{DRM} , V _R =V _{RRM}	T _j =25°C	≤5				μA
I _{RRM}		T _j =125°C	≤1				mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case(AC)	1.8	°C/W

PARAMETER CHARACTERISTIC CURVE

FIG.1 Maximum power dissipation versus RMS on-state current

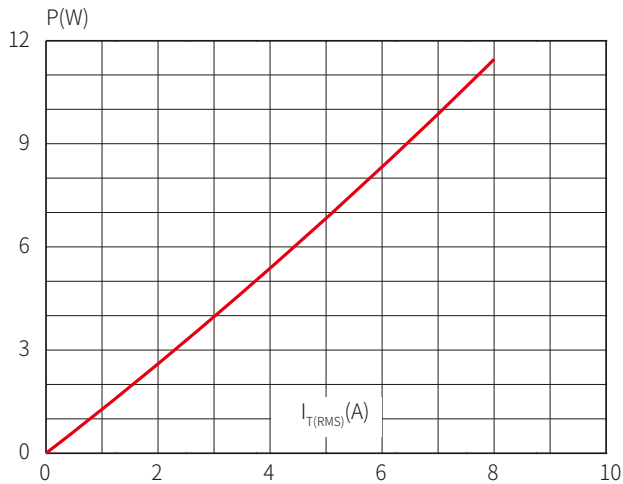


FIG.2: RMS on-state current versus case temperature

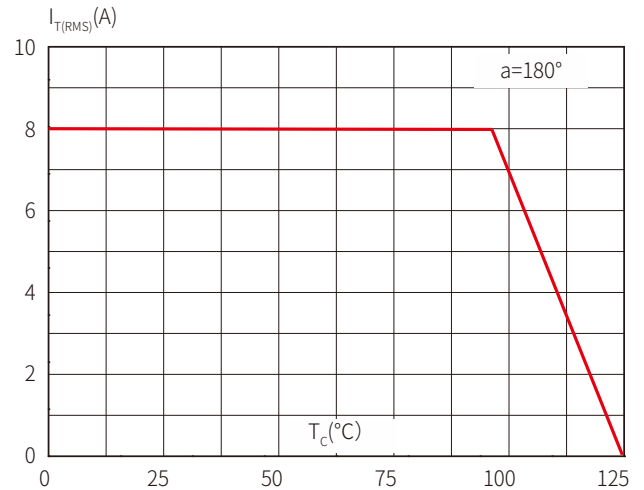


FIG.3: Surge peak on-state current versus number of cycles

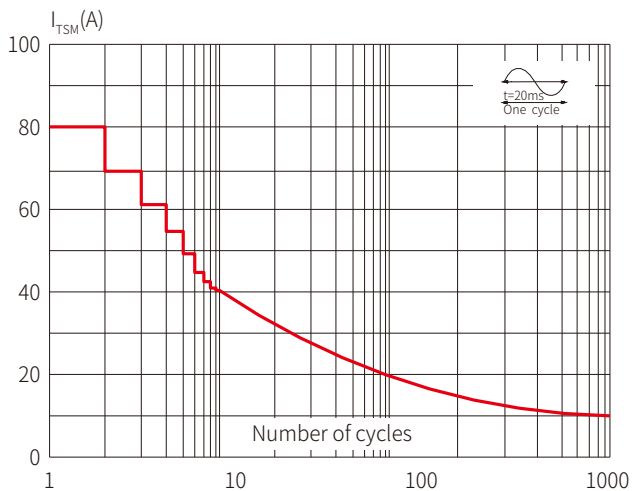


FIG.4 On-state characteristics (maximum values)

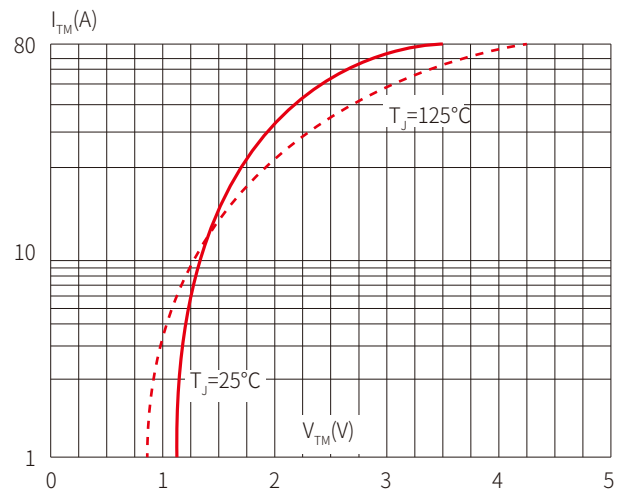


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$ and corresponding value of I^2t ($dI/dt < 50\text{A}/\mu\text{s}$)

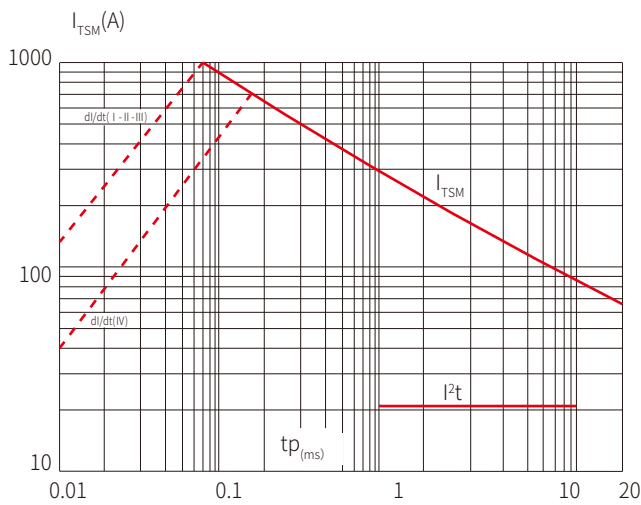


FIG.6 Relative variations of gate trigger current versus junction temperature

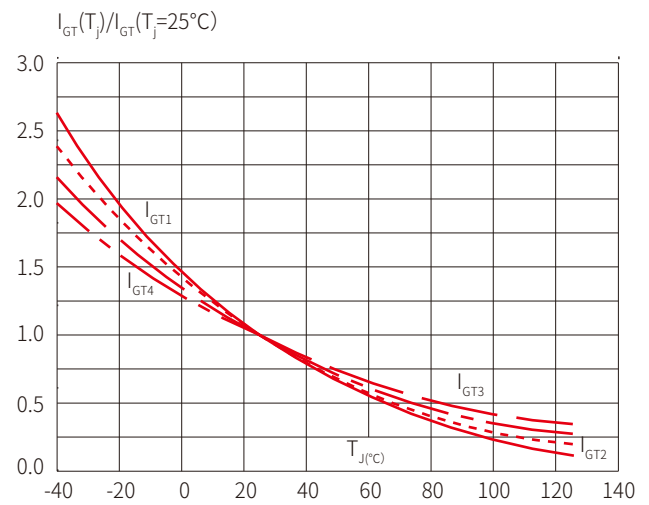


FIG.7 Relative variations of holding current versus junction temperature

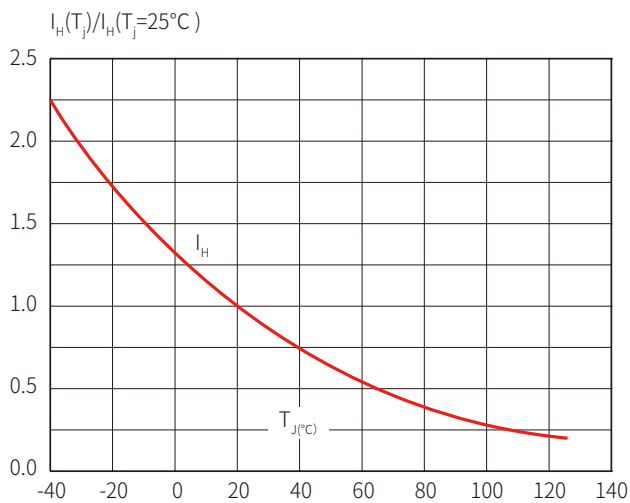
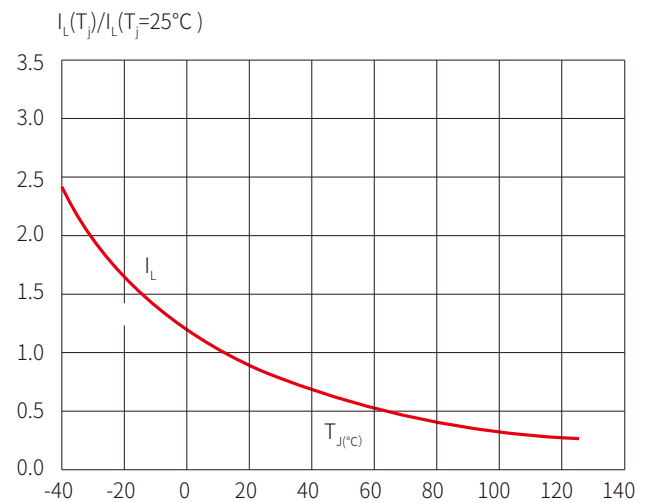
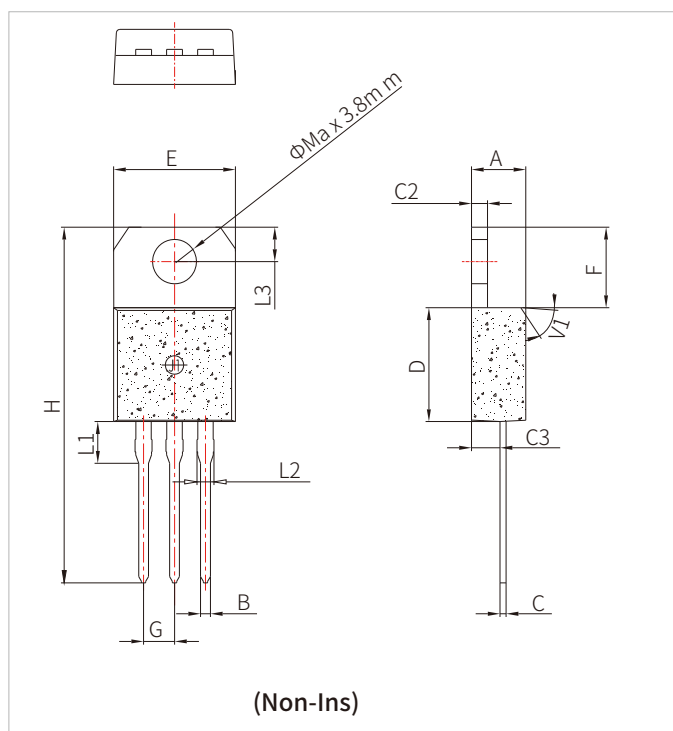


FIG.8 Relative variations of latching current versus junction temperature



TO-220B PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.70	0.169		0.185
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.60		10.4	0.378		0.409
F	6.20		6.60	0.222		0.260
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

ORDERING INFORMATION

Part Number	Package	Qty/pcs		
		Tube	Inner Box	Carton
STB8Q80D(E/F/G)	TO-220B	50	1000	5000

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